PH515 – Lecture Notes (jb)

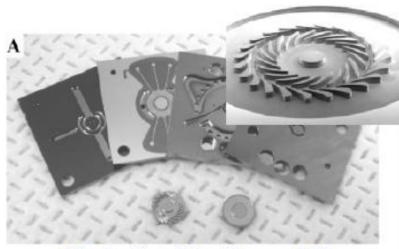
MEMS Fabrication Process 27-1-2015

Consists of four distinct processes

- 1. Substrate starting point
- 2. Patterning Lithography
- 3. Additive process Deposition
- 4. Subtractive process Etching. Together they form what is known as Micromachining

Micromachining combines

Lithography, Thin Film processing and Sacrificial etching to form mechanical devices



Microturbine, Schmidt group MIT

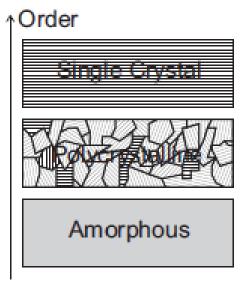
Materials for MEMS

Classified into three categories :

<u>Crystalline material</u>: Highest order. Periodic arrangement of atoms in space following one of the 14 Bravais' lattice. The material properties are highly reproducible . However, the properties will depend on the direction with in the crystal and hence the material is anisotropic.

<u>Amorphous material:</u> Disordered form. Clusters of crystals being of a few atoms only. Properties are more stable and also independent of the direction - material is isotropic.

<u>Polycrystalline material:</u> Material does not crystallize in a continuous film, but in small clusters of crystals called grains, each grain having a different orientation than its neighbour. In general, some grain directions may be preferred depending on the process, and thus the material properties vary considerably with the process.



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Materials for MEMS

MEMS utilizes the same materials used in microelectronics (IC) for device fabrication and we will concentrate o n these materials here

- 1. Silicon
- 2. Poly crystalline Silicon
- 3. Oxides of Silicon
- 4. Poly crystalline or amorphous dielectric layers
- 5. Silicon Nitride
- 6. Polymers
- 7. Metal thin films.

Materials for MEMS

Choice of Material depends on properties like :

- 1. Low processing temperature
- 2. Compatibility with other materials
- 3. Possibility to obtain thick layers
- 4. Patterning possibilities

And also application dependent properties :

1. Optics : May need transparent substrate

- 2. Bio : Compatibility
- 3. Sensors : Piezoelectric or piezoresistive

Why Silicon?

Silicon is an excellent mechanical material:

- 1. strong (comparable) as steel but lighter than steel
- 2. Has large critical stress and can recover from large strain
- 3. Has large piezoresistive coefficient (Sensor)
- 4. Transparent at the telecommunication wavelengths (Optical)
- 5. Young's modulus varies with crystallographic direction

(mechanical)

Silicon Crystal Structure

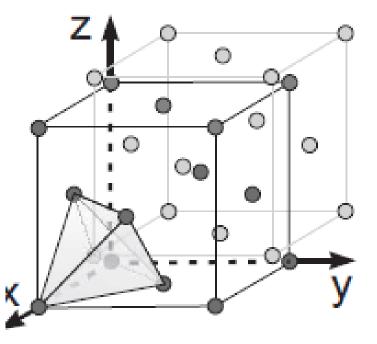
Face centred Cubic lattice

2 atoms per unit cell

Tetrahedron configuration - each Si atom has

four neighbours

Lattice constant = 5.43A at 300K



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Silicon Crystal Structure

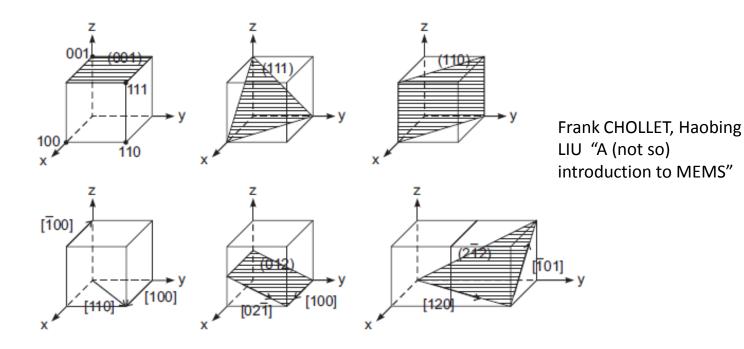
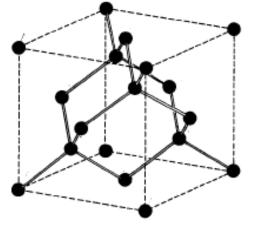


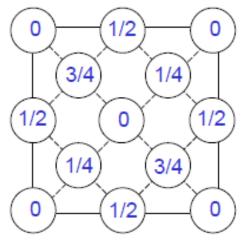
Figure 3.4: Lattice points coordinate, planes and directions in the cubic lattice of silicon.

A plane is identified by three indices (hkl), set of equivalent planes {h k l} Specific directions normal to the plane [h k l], equivalent directions <h k l>

Silicon Crystal Structure

Silicon Crystallography





Angle between the planes determined from

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$$\alpha = \cos^{-1} \frac{h_1 h_2 + k_1 k_2 + l_1 l_2}{\sqrt{h_1^2 + k_1^2 + l_1^2} \sqrt{h_2^2 + k_2^2 + l_2^2}}$$

Other Materials

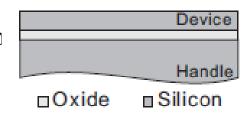
Silicon Oxide: Amorphous film – transparent, thermally and electrically insulating

- : Smallest coefficient of thermal expansion among all known materials
- : Good use in MEMS Fabrication where oxide support is required
 - e.g. Thermally insulate a pixel of a thermal cameral

Silicon on Insulator: Allows producing complete devices in

a simple process

: Optical switch where mobile mirror, actuator and fiber alignment done with single step.



Silicon Nitride		Frank CHOLLET, Haobing LIU "A (not so) introduction to MEMS"	
InP	: Photonic capabilities for tunable laser		
Quartz	: Piezoelectric effect		
Glass	: Only second to silicon in MEMS use. Can	form tight bond	
	with Si and also biocompatible		
Polyemer	: Bio MEMS – provide biodegradability, thermoplastic		
	property for molding		
Metals	; Used when high conductivity is required. Easy to form films		

Requires Micrometric Features.

Traditional methods

Milling
Drilling
Casting

Can not be used due to the small scale involved.

Feature Size similar to that in ICs Microelectronic fabrication techniques useful.

Will discuss some of these techniques here !!!

Photolithography:

- 1. Photo resist spinning
- 2. Optical Exposure through a mask
- 3. Developing to dissolve exposed resist
- 4. Bake to drive off solvents
- 5. Remove using solvents or plasma etching

Photo Mask:

1. Lay out of the preferred pattern generated by CAD file

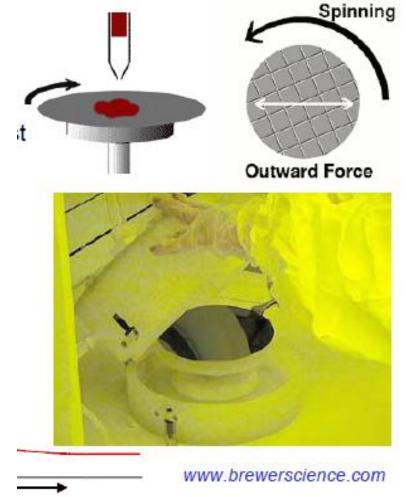
2. Use laser or e-beam to generate the mask on preferred material – generally SiN

Spin coating resist:

Usually a polymer
Positive or negative photo resist

Thickness of the resist depends on

- 1. Concentration
- 2. Spin speed
- 3. Spin Time



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Photolithography: Creating the pattern

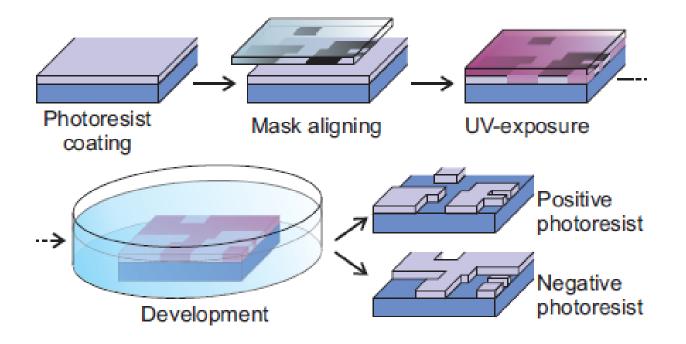
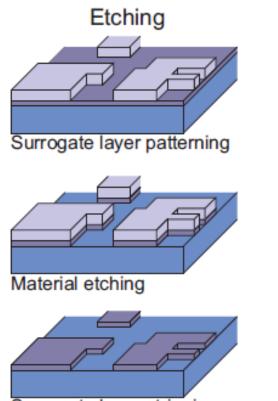


Figure 3.1: Photo-patterning in positive and negative photoresist.

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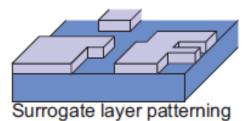
Photolithography: Transferring the pattern

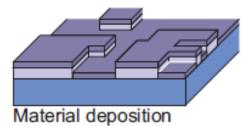


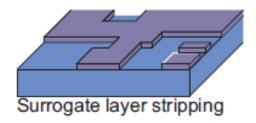
Surrogate layer stripping

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Lift-off







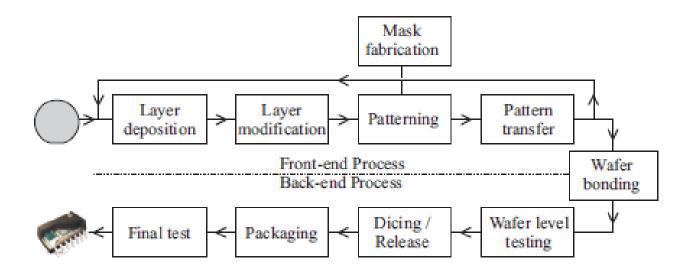


Figure 3.3: General view of MEMS production process.

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